

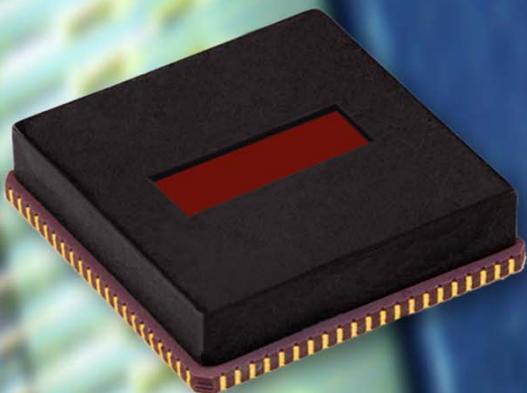


Infrared Materials
The Leader in High Performance IR Detectors

PbSe

256 Pixel MWIR Linear Array

1.2 to 5.5 Microns



Integral TEC | -20°C Operation (45 Degrees DT)

256 Channel Multiplexer (MUX)

WWW.INFRAREDMATERIALS.COM

707-620-0160

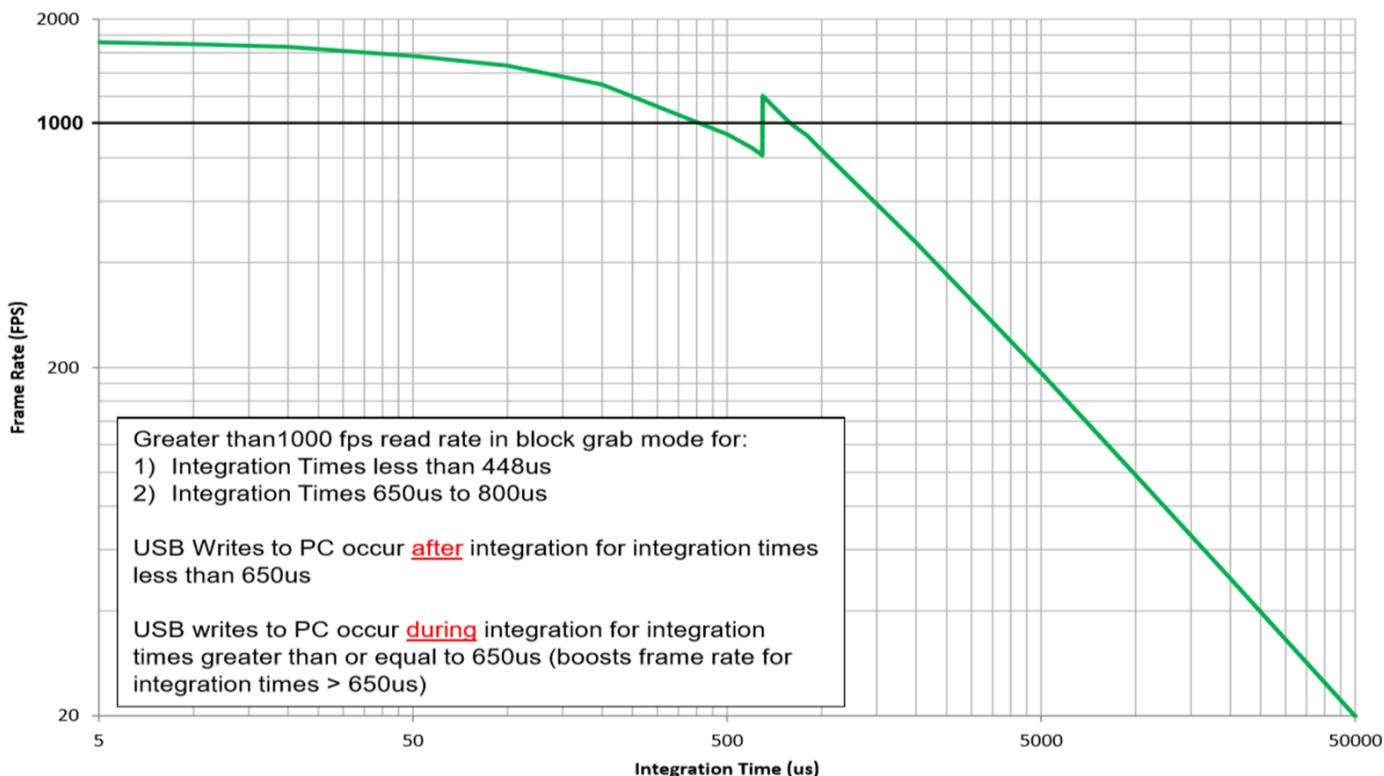


PbSe MWIR PHOTOCONDUCTIVE IR ARRAYS | 1.2 - 5.5 MICRONS



Array Mechanical Characteristics			
Optical Interface	84-pin Leadless Chip Carrier (LCC), 0.317" height, 1.150" Square	--	
Window	0.50 mm Thick Silicon with Long Wave Pass (LWP) Anti-Reflective Coating	--	
Array Type	PbSe Quantum Photoconductor	--	
*PbS versions also available for spectral sensitivity from 1.2 - 3.3 Microns			
Resolution	256 x 1	--	
Pixel Size	0.040 x 0.450	--	mm
Pixel Options	0.040 x 0.040	(Square Pixel)	mm
	0.040 x 4.50	(Long Pixel)	mm
Array Length	12.85	--	mm
Pixel Pitch	0.050	(On centers)	mm
Pixel Operability	> 98%	--	
Cooling Element	Thermoelectric Cooler (TEC)	1-Stage, 10 Watt, RoHS	5.0 VDC @ 2.0 Amps
Field of View (FOV)	> 40	--	Degrees
Readout Electronics (ROIC)			
ADIC PC06 R6 Array Controller	32 Bit microcontroller (80 MHz)	16 Bit A/D Converter	On Board EEPROM
External Hardware Trigger Input	External Shutter Control	Auto Calibration Feature	Integrated TE Cooler Board
Default Temp range -20 to +25°C	Control Stability to ± 5 mK	Array Software & SDK Available	
Readout Method	Multiplexer, 256 Channel, DC Integrating w/ Global & 8 Bit Per Pixel Dark Current Correction		
Readout Control / Windowing	Feature to readout all 256 pixels or a user defined value, e.g., 2, 8, 16, 32, 64, 128, etc.		
Integration Time Range**	4 (Min.)	--	μs
	210 (Max.)	--	ms
	**Digitally selectable in 3.2 μs steps.		
Frame Rate***	Sample rates up to 1700 frames per second, 1 to 64K block selectable		
	***Maximum frame rate achieved at the minimum integration time		

Frame Rate vs. Integration Time (Block Grab Mode)

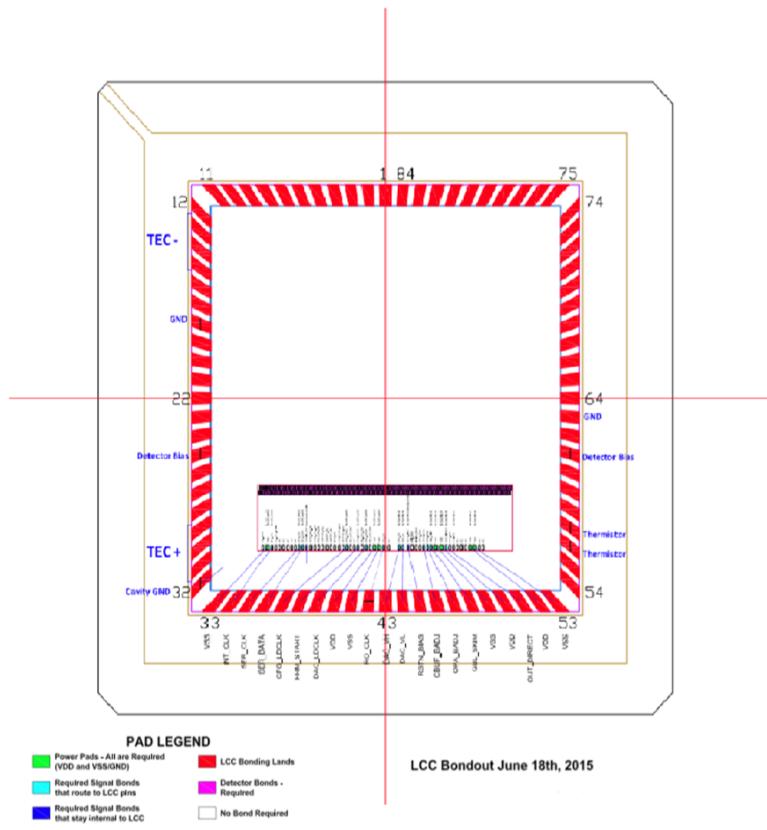
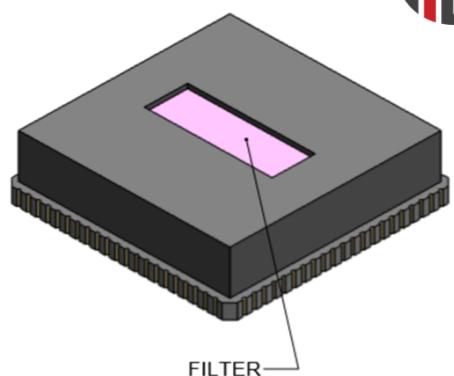
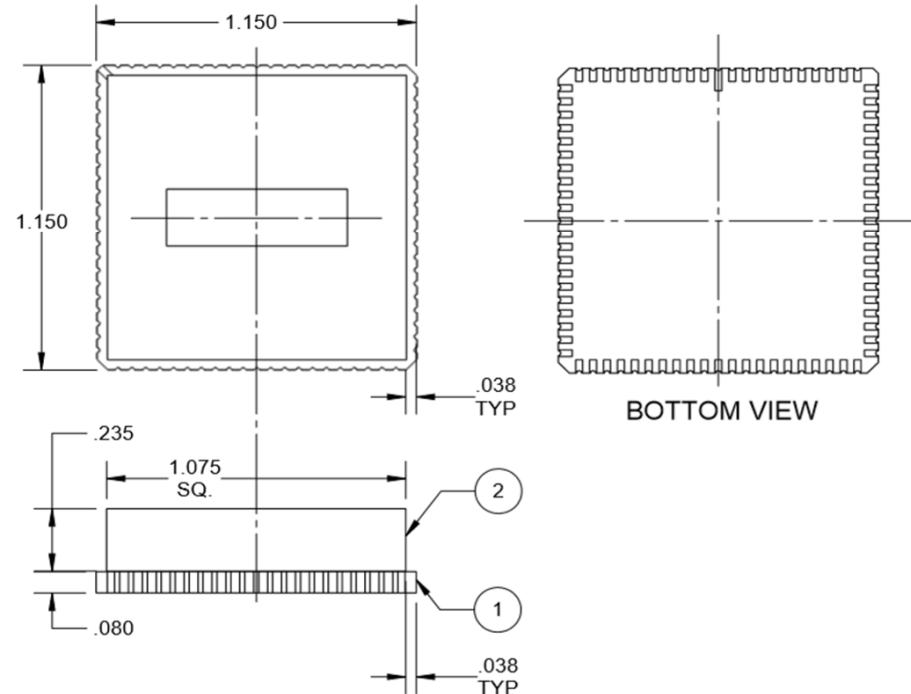


PbSe MWIR PHOTOCONDUCTIVE IR ARRAYS | 1.2 - 5.5 MICRONS



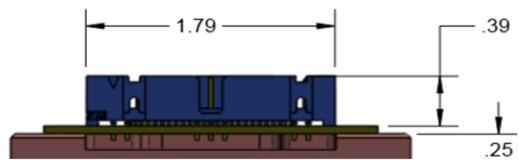
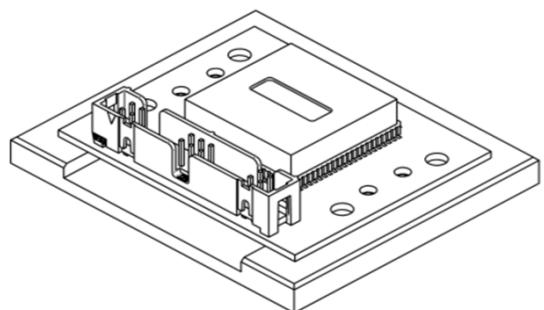
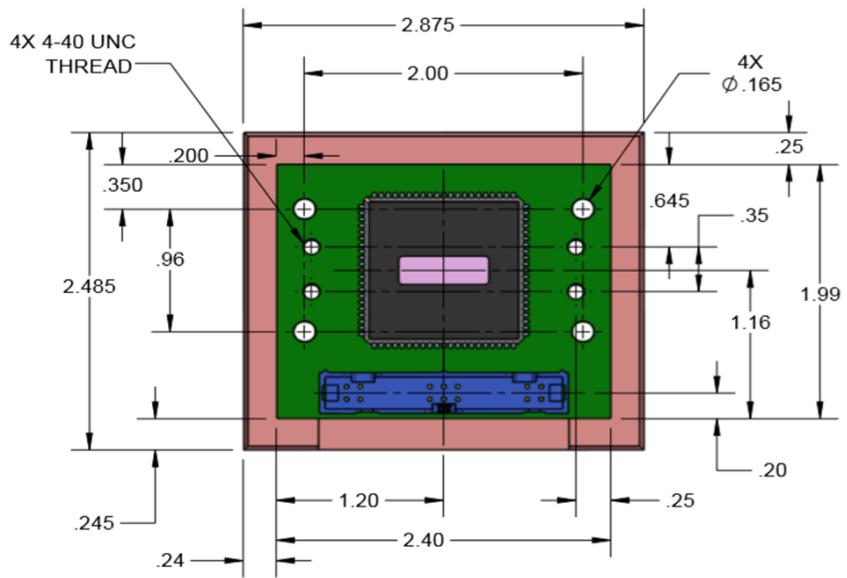
Operating Modes	Integrate While Read (IWR)		
	Integrate Then Read (ITR)		
Compatibility	Windows DLL Software Interface, Linux Compatible		
	Programming languages supported: Visual C#, Visual C++, and more.		
Interface Protocol	USB 2.0 (Ethernet, SPI, RS485 Serial Communication Interfaces Under Development)		
Power Requirement:			
Data Acquisition / TEC Controller	15 VDC	1.6 A	--
Spectral Characteristics			
Operating Range (λ)	1.2**	5.5	Microns
	**Cut-on wavelength is dependent upon the window material		
	Other window options are available for wavelength sensitivity at or below 1.0 Microns.		
Wavelength Peak (λ_{pk})	>= 4.1 (Min.)	<= 4.3 (Max.)	Microns
Electrical Performance Characteristics			
Pixel Resistance Range +25°C (Typ.)	10	11	MΩ
-20°C (Typ.)	50	60	MΩ
D* (D-Star) Detectivity +25°C	>= 1.8 x 10 ¹⁰ (Min.)	No Upper Limit	cm Hz ^{1/2} w ⁻¹
Responsivity	2.5 x 10 ⁵ (min.)	4.0 x 10 ⁵ (Typ.)	V/W
Response Uniformity	± 15 of Mean	--	%
Quantum Efficiency (QE)	2	--	%
Time Constant (T_c)	2 @ +25°C (Typ.)	20 @ -20°C (Max.)	uSec
NEP	No Data	--	pW
General Specifications			
Operating Temperature	-20	--	°C
Operational Temperature Range	-50	+85	°C
Maximum Incident Light	1x10 ⁻³	--	W/cm2
Storage Temperature	-50 (Min.)	+85 (Max.)	°C
Thermistor Resistance	10 ± 5% @ +25°C	Not calibrated	KΩ
PbSe ARRAY DEVELOPMENT SYSTEM (DS)			
Development System Kit Includes:			
256 Element PbSe Array and Headboard			
USB Electronic Controller Board R6, Ribbon Cable, USB Cable			
Copper Mounting Block			
Copper Heatsink with Integrated Fan			
System Power Supply Module (12V @ 1A)			
Array Controller GUI Software & SDK Library			
Users Manual (Also available on website)			
OPERATING MODES:	Pixel Stream Output		
	Spectrometer Mode		
	Push Broom Imager		
FEATURES:			
External Hardware Trigger Input			
External Shutter Control			
Auto Calibration Feature			
Integrated TE Cooler Board (Control Stability to ± 5 mK)			
32 Bit microcontroller (80 MHz)			
16 Bit A/D Converter			
ADDITIONAL DEVELOPMENTS:			
Linear Variable Filter (LVF) Integration of PbSe Versions for 2.5 - 5.5 Micron Operating Range			
Ethernet Communication Protocol Under Development			
ADDITIONAL TOOLS:			
3D Model Drawing Available Upon Request for Mechanical Design Considerations			

PbSe MWIR PHOTOCONDUCTIVE IR ARRAYS | 1.2 - 5.5 MICRONS

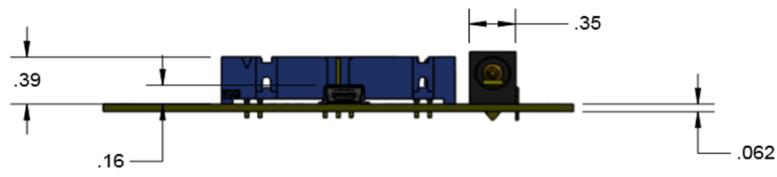
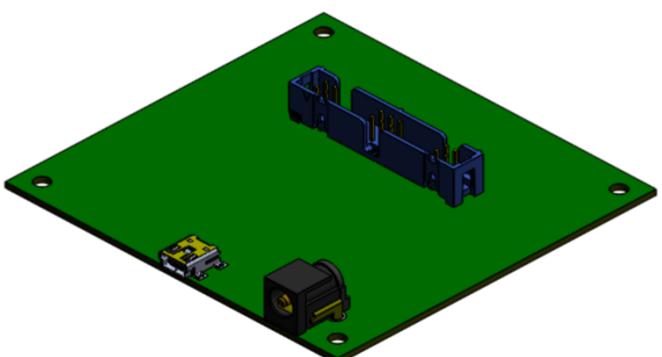
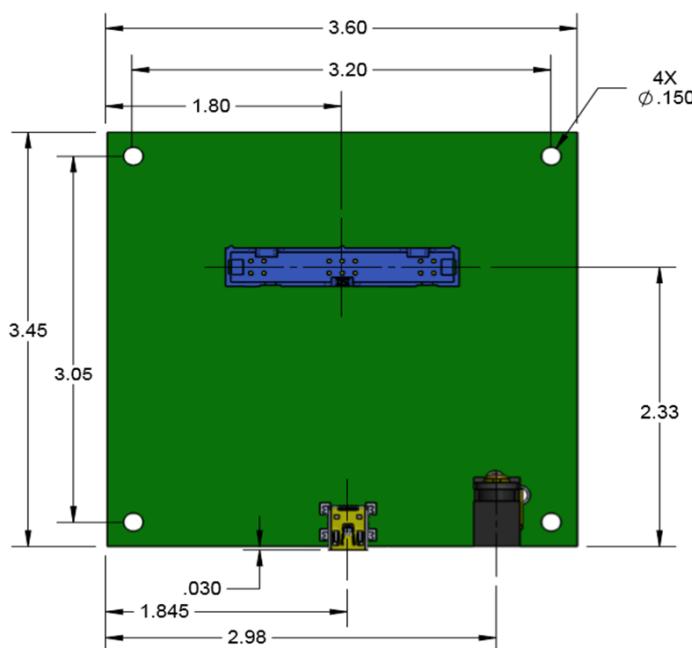


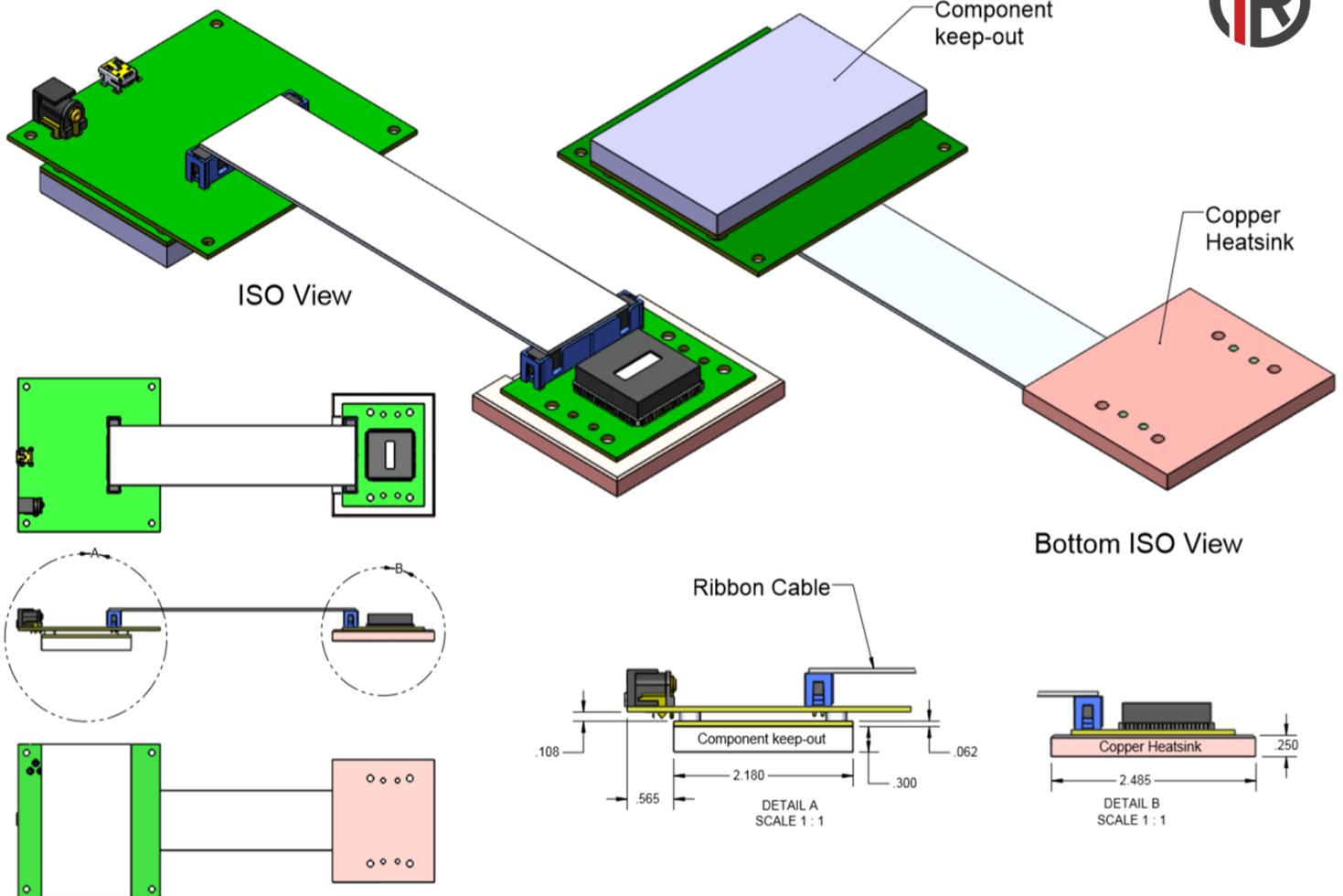


84 LEAD PCB ASSEMBLY



ARRAY R6 ASSEMBLY





TRIGGER INPUT

